Analog Multiplexer/ Demultiplexer

High-Performance Silicon-Gate CMOS

The MC74LVX8053 utilizes silicon–gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF leakage currents. This analog multiplexer/demultiplexer controls analog voltages that may vary across the complete power supply range (from V_{CC} to GND).

The LVX8053 is similar in pinout to the high–speed HC4053A, and the metal–gate MC14053B. The Channel–Select inputs determine which one of the Analog Inputs/Outputs is to be connected, by means of an analog switch, to the Common Output/Input. When the Enable pin is HIGH, all analog switches are turned off.

The Channel-Select and Enable inputs are compatible with standard CMOS outputs; with pull-up resistors they are compatible with LSTTL outputs.

This device has been designed so that the ON resistance (R_{on}) is more linear over input voltage than R_{on} of metal-gate CMOS analog switches.

Features

- Fast Switching and Propagation Speeds
- Low Crosstalk Between Switches
- Diode Protection on All Inputs/Outputs
- Analog Power Supply Range $(V_{CC} GND) = 2.5$ to 6.0 V
- Digital (Control) Power Supply Range $(V_{CC} GND) = 2.5$ to 6.0 V
- Improved Linearity and Lower ON Resistance Than Metal–Gate Counterparts
- Low Noise
- In Compliance With the Requirements of JEDEC Standard No. 7A
- Chip Complexity: LVX8053 156 FETs or 39 Equivalent Gates
- These Devices are Pb-Free and are RoHS Compliant



ON Semiconductor®

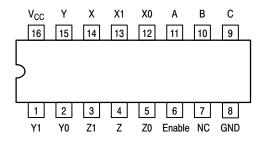
http://onsemi.com



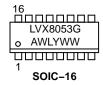


SOIC-16 D SUFFIX CASE 751B TSSOP-16 DT SUFFIX CASE 948F

PIN ASSIGNMENT



MARKING DIAGRAMS





TSSOP-16

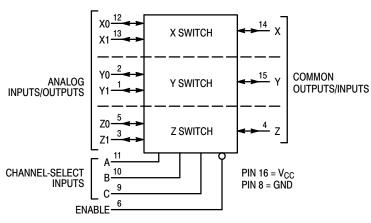
LVX8053 = Specific Device Code A = Assembly Location

WL, L = Wafer Lot Y = Year WW, W = Work Week G or • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.



NOTE: This device allows independent control of each switch. Channel–Select Input A controls the X–Switch, Input B controls the Y–Switch and Input C controls the Z–Switch

FUNCTION TABLE - MC74LVX8053

Control Inputs							
Enable	С	Select B	t A	ON	Chanr	ole	
Lilable	<u> </u>			Oi	Citatii	1612	
L	L	L	L	Z0	Y0	X0	
L	L	L	Н	Z0	Y0	X1	
L	L	Н	L	Z0	Y1	X0	
L	L	Н	Н	Z0	Y1	X1	
L	н	L	L	Z1	Y0	X0	
L	н	L	Н	Z1	Y0	X1	
L	н	Н	L	Z1	Y1	X0	
L	н	Н	Н	Z1	Y1	X1	
Н	X	Χ	Χ	NONE			

X = Don't Care

LOGIC DIAGRAM Triple Single-Pole, Double-Position Plus Common Off

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Positive DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V _{IS}	Analog Input Voltage	–0.5 to V _{CC} + 0.5	V
V _{in}	Digital Input Voltage (Referenced to GND)	–0.5 to V _{CC} + 0.5	V
I	DC Current, Into or Out of Any Pin	±20	mA
P _D	Power Dissipation in Still Air, SOIC Package† TSSOP Package†	500 450	mW
T _{stg}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

†Derating: SOIC Package: -7 mW/°C from 65° to 125°C TSSOP Package: -6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC} .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or $V_{\rm CC}$). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Max	Unit
V _{CC}	Positive DC Supply Voltage (Referenced to GND)	2.5	6.0	V
V _{IS}	Analog Input Voltage	0.0	V _{CC}	V
V _{in}	Digital Input Voltage (Referenced to GND)	GND	V _{CC}	V
V _{IO} *	Static or Dynamic Voltage Across Switch		1.2	V
T _A	Operating Temperature Range, All Package Types	– 55	+ 85	°C
t _r , t _f	Input Rise/Fall Time (Channel Select or Enable Inputs)			ns/V
	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

*For voltage drops across switch greater than 1.2 V (switch on), excessive V_{CC} current may be drawn; i.e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

DC CHARACTERISTICS — Digital Section (Voltages Referenced to GND)

			v _{cc}	Guaranteed Limit			
Symbol	Parameter	Condition	v	-55 to 25°C	≤ 85°C	≤ 125°C	Unit
V _{IH}	Minimum High-Level Input Voltage, Channel-Select or Enable Inputs	R _{on} = Per Spec	2.5 3.0 4.5 5.5	1.50 2.10 3.15 3.85	1.50 2.10 3.15 3.85	1.50 2.10 3.15 3.85	V
V _{IL}	Maximum Low–Level Input Voltage, Channel–Select or Enable Inputs	R _{on} = Per Spec	2.5 3.0 4.5 5.5	0.5 0.9 1.35 1.65	0.5 0.9 1.35 1.65	0.5 0.9 1.35 1.65	V
I _{in}	Maximum Input Leakage Current, Channel–Select or Enable Inputs	V _{in} = V _{CC} or GND,	5.5	±0.1	±1.0	±1.0	μΑ
Icc	Maximum Quiescent Supply Current (per Package)	Channel Select, Enable and $V_{IS} = V_{CC}$ or GND; $V_{IO} = 0$ V	5.5	4	40	160	μΑ

DC ELECTRICAL CHARACTERISTICS Analog Section

			V _{CC}	Guara	anteed Lim	it	
Symbol	Parameter	Test Conditions	V	-55 to 25°C	≤ 85°C	≤ 125°C	Unit
R _{on}	Maximum "ON" Resistance	$\begin{split} &V_{\text{In}} = V_{\text{IL}} \text{ or } V_{\text{IH}} \\ &V_{\text{IS}} = V_{\text{CC}} \text{ to GND} \\ & I_{\text{S}} \leq 10.0 \text{ mA (Figures 1, 2)} \end{split}$	3.0 4.5 5.5	40 30 25	45 32 28	50 37 30	Ω
		$\begin{aligned} &V_{in} = V_{IL} \text{ or } V_{IH} \\ &V_{IS} = V_{CC} \text{ or GND (Endpoints)} \\ & I_{S} \leq 10.0 \text{ mA (Figures 1, 2)} \end{aligned}$	3.0 4.5 5.5	30 25 20	35 28 25	40 35 30	
ΔR_{on}	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	$V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{IS} = 1/2 (V_{CC} - GND)$ $ I_S \le 10.0 \text{ mA}$	3.0 4.5 5.5	15 8.0 8.0	20 12 12	25 15 15	Ω
I _{off}	Maximum Off–Channel Leakage Current, Any One Channel	$V_{in} = V_{IL} \text{ or } V_{IH};$ $V_{IO} = V_{CC} \text{ or GND};$ Switch Off (Figure 3)	5.5	0.1	0.5	1.0	μΑ
	Maximum Off–Channel Leakage Current, Common Channel	$V_{IO} = V_{IL} \text{ or } V_{IH};$ $V_{IO} = V_{CC} \text{ or GND};$ Switch Off (Figure 4)	5.5	0.1	1.0	2.0	
I _{on}	Maximum On–Channel Leakage Current, Channel–to–Channel	$V_{in} = V_{IL}$ or V_{IH} ; Switch-to-Switch = V_{CC} or GND; (Figure 5)	5.5	0.1	1.0	2.0	μΑ

AC CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 3 \text{ ns}$)

			v _{cc}	Guara	nteed Lin	nit	
Symbol	Parameter		V	–55 to 25°C	≤ 85°C	≤ 125°C	Unit
t _{PLH} ,	Maximum Propagation Delay, Channel-Select t	o Analog Output	2.5	30	35	40	ns
t _{PHL}	(Figure 9)		3.0	20	25	30	
			4.5	15	18	22	
			5.5	15	18	20	
t_{PLH} ,	Maximum Propagation Delay, Analog Input to A	nalog Output	2.5	4.0	6.0	8.0	ns
t _{PHL}	(Figure 10)		3.0	3.0	5.0	6.0	
			4.5	1.0	2.0	2.0	
			5.5	1.0	2.0	2.0	
t_{PLZ} ,	Maximum Propagation Delay, Enable to Analog	Output	2.5	30	35	40	ns
t _{PHZ}	(Figure 11)		3.0	20	25	30	
			4.5	15	18	22	
			5.5	15	18	20	
t _{PZL} ,	Maximum Propagation Delay, Enable to Analog	Output	2.5	20	25	30	ns
t _{PZH}	(Figure 11)		3.0	12	14	15	
			4.5	8.0	10	12	
			5.5	8.0	10	12	
C _{in}	Maximum Input Capacitance, Channel-Select of	or Enable Inputs		10	10	10	pF
C _{I/O}	Maximum Capacitance	Analog I/O		35	35	35	pF
	(All Switches Off)	Common O/I		50	50	50	
		Feedthrough		1.0	1.0	1.0	

		Typical @ 25°C, V _{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Figure 13)*	45	pF

^{*} Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

ADDITIONAL APPLICATION CHARACTERISTICS (GND = 0 V)

			Vcc	Limit*	
Symbol	Parameter	Condition		25°C	Unit
BW	Maximum On–Channel Bandwidth or Minimum Frequency Response	f _{in} = 1MHz Sine Wave; Adjust f _{in} Voltage to Obtain 0dBm at V _{OS} ; Increase f _{in} Frequency Until dB	3.0	120	MHz
	(Figure 6)	Meter Reads $-3dB$; R _L = 50Ω , C _L = $10pF$	4.5 5.5	120 120 120	
-	Off-Channel Feedthrough Isolation (Figure 7)	f_{in} = Sine Wave; Adjust f_{in} Voltage to Obtain 0dBm at V_{IS} f_{in} = 10kHz, R_L = 600 Ω , C_L = 50pF	3.0 4.5 5.5	-50 -50 -50	dB
		$f_{in} = 1.0 MHz, R_L = 50 \Omega, C_L = 10 pF$	3.0 4.5 5.5	-37 -37 -37	
_	Feedthrough Noise. Channel–Select Input to Common I/O (Figure 8)	$V_{in} \le$ 1MHz Square Wave ($t_f = t_f = 6ns$); Adjust R _L at Setup so that I _S = 0A; Enable = GND R _L = 600Ω , C _L = $50pF$	3.0 4.5 5.5	25 105 135	mV _{PP}
		$R_L = 10k\Omega$, $C_L = 10pF$	3.0 4.5 5.5	35 145 190	
_	Crosstalk Between Any Two Switches (Figure 12)	f_{in} = Sine Wave; Adjust f_{in} Voltage to Obtain 0dBm at V_{IS} f_{in} = 10kHz, R_L = 600 Ω , C_L = 50pF	3.0 4.5 5.5	-50 -50 -50	dB
		$f_{in} = 1.0 MHz, R_L = 50 \Omega, C_L = 10 pF$	3.0 4.5 5.5	-60 -60 -60	
THD	Total Harmonic Distortion (Figure 14)	$\begin{aligned} f_{\text{in}} = 1 \text{kHz, R}_{L} = 10 \text{k}\Omega, \ C_{L} = 50 \text{pF} \\ \text{THD} = \text{THD}_{\text{measured}} - \text{THD}_{\text{source}} \\ V_{\text{IS}} = 2.0 \text{V}_{\text{PP}} \text{ sine wave} \\ V_{\text{IS}} = 4.0 \text{V}_{\text{PP}} \text{ sine wave} \\ V_{\text{IS}} = 5.5 \text{V}_{\text{PP}} \text{ sine wave} \end{aligned}$	3.0 4.5 5.5	0.10 0.08 0.05	%

^{*}Limits not tested. Determined by design and verified by qualification.

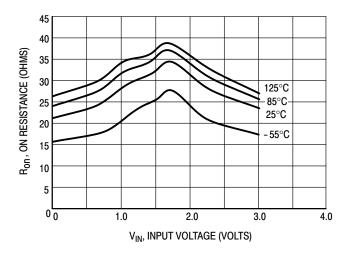


Figure 1a. Typical On Resistance, V_{CC} = 3.0 V

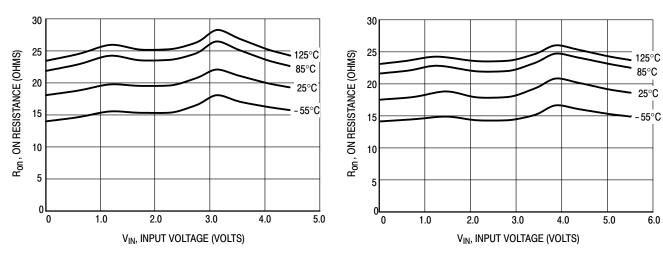


Figure 1b. Typical On Resistance, $V_{CC} = 4.5 \text{ V}$

Figure 1c. Typical On Resistance, $V_{CC} = 5.5 \text{ V}$

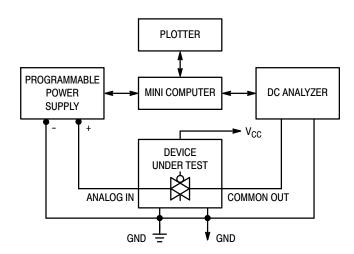


Figure 2. On Resistance Test Set-Up

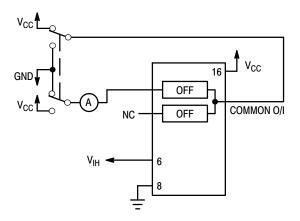


Figure 3. Maximum Off Channel Leakage Current, Any One Channel, Test Set-Up

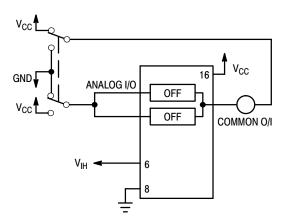


Figure 4. Maximum Off Channel Leakage Current, Common Channel, Test Set-Up

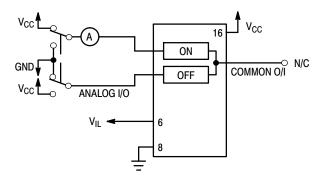


Figure 5. Maximum On Channel Leakage Current, Channel to Channel, Test Set-Up

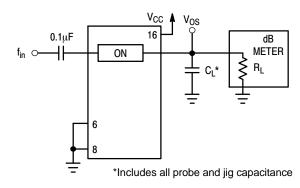


Figure 6. Maximum On Channel Bandwidth, Test Set-Up

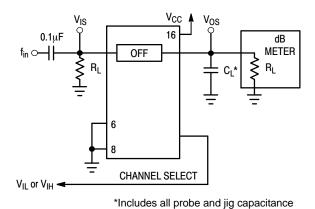
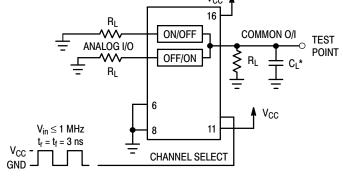


Figure 7. Off Channel Feedthrough Isolation, Test Set-Up



*Includes all probe and jig capacitance

Figure 8. Feedthrough Noise, Channel Select to Common Out, Test Set-Up

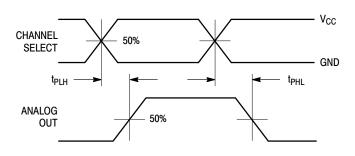
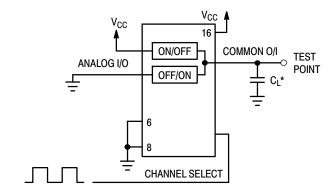


Figure 9a. Propagation Delays, Channel Select to Analog Out



*Includes all probe and jig capacitance

Figure 9b. Propagation Delay, Test Set-Up Channel Select to Analog Out

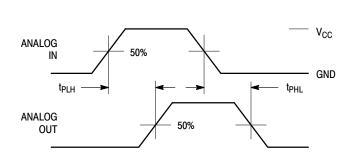


Figure 10a. Propagation Delays, Analog In to Analog Out

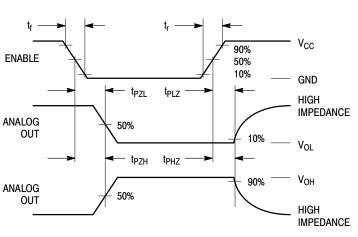
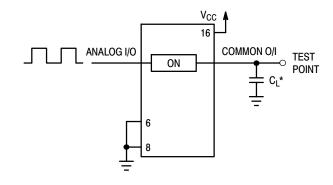


Figure 11a. Propagation Delays, Enable to Analog Out



*Includes all probe and jig capacitance

Figure 10b. Propagation Delay, Test Set-Up
Analog In to Analog Out

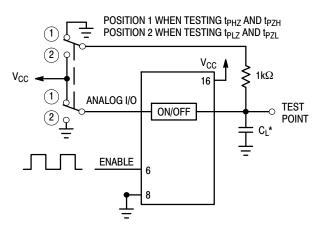
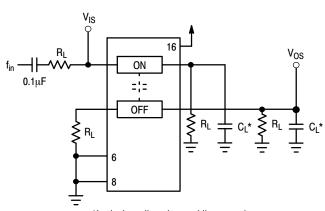


Figure 11b. Propagation Delay, Test Set-Up
Enable to Analog Out



*Includes all probe and jig capacitance

Figure 12. Crosstalk Between Any Two Switches, Test Set-Up

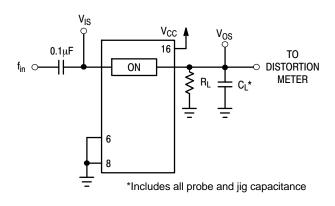


Figure 14a. Total Harmonic Distortion, Test Set-Up

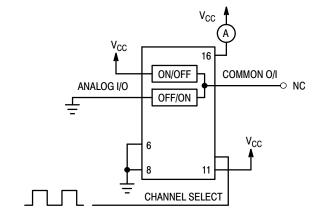


Figure 13. Power Dissipation Capacitance, Test Set-Up

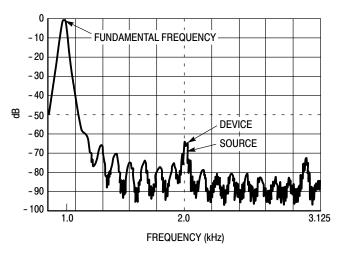


Figure 14b. Plot, Harmonic Distortion

APPLICATIONS INFORMATION

The Channel Select and Enable control pins should be at V_{CC} or GND logic levels. V_{CC} being recognized as a logic high and GND being recognized as a logic low. In this example:

$$V_{CC} = +5V = logic \ high$$

 $GND = 0V = logic \ low$

The maximum analog voltage swing is determined by the supply voltages V_{CC} . The positive peak analog voltage should not exceed V_{CC} . Similarly, the negative peak analog voltage should not go below GND. In this example, the difference between V_{CC} and GND is five volts. Therefore, using the configuration of Figure 15, a maximum analog signal of five volts peak—to—peak can be controlled. Unused analog inputs/outputs may be left floating (i.e., not

connected). However, tying unused analog inputs and outputs to V_{CC} or GND through a low value resistor helps minimize crosstalk and feedthrough noise that may be picked up by an unused switch.

Although used here, balanced supplies are not a requirement. The only constraints on the power supplies are that:

$$V_{CC} - GND = 2$$
 to 6 volts

When voltage transients above V_{CC} and/or below GND are anticipated on the analog channels, external Germanium or Schottky diodes (D_x) are recommended as shown in Figure 16. These diodes should be able to absorb the maximum anticipated current surges during clipping.

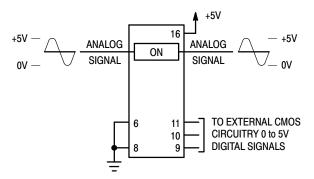


Figure 15. Application Example

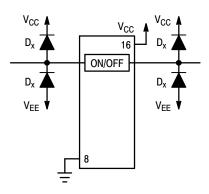
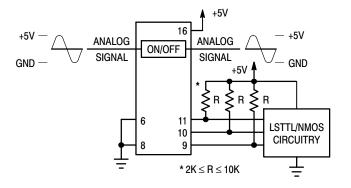
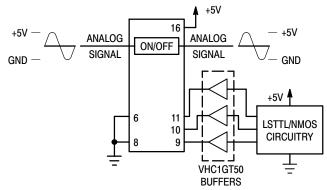


Figure 16. External Germanium or Schottky Clipping Diodes



a. Using Pull-Up Resistors



b. Using HCT Interface

Figure 17. Interfacing LSTTL/NMOS to CMOS Inputs

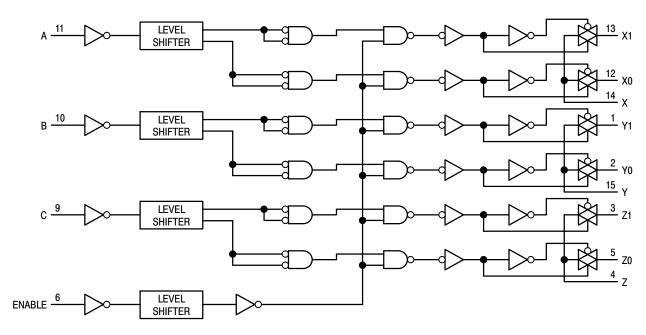


Figure 18. Function Diagram, LVX8053

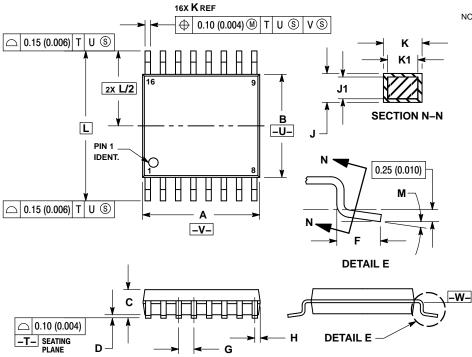
ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LVX8053DR2G	SOIC-16 (Pb-Free)	2500 Tape & Reel
MC74LVX8053DTR2G	TSSOP-16 (Pb-Free)	2500 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TSSOP-16 CASE 948F **ISSUE B**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 - 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS.

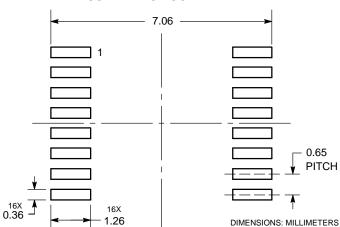
 - FLASH. PROTRUSIONS OR GATE BURRS.
 MOLD FLASH OR GATE BURRS SHALL NOT
 EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE
 INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
 NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE
 DAMBAR PROTRUSION. ALLOWABLE
 DAMBAR PROTRUSION SHALL BE 0.08
 (0.003) TOTAL IN EXCESS OF THE K
 DIMENSION AT MAXIMUM MATERIAL
 CONDITION. CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR

 - REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026	BSC	
Н	0.18	0.28	0.007	0.011	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40		0.252 BSC		
М	0 °	8 °	٥°	8 °	

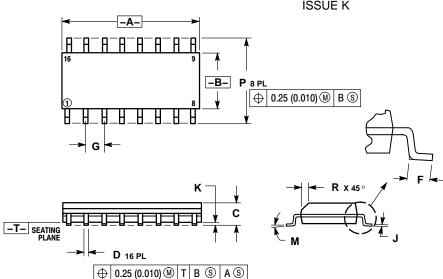
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOIC-16 CASE 751B-05



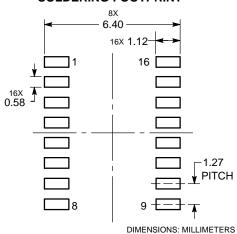
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD
- PROTRUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	1.27 BSC		BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the 👊 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative